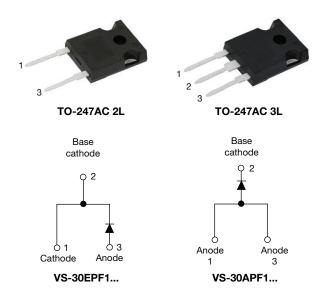
Vishay Semiconductors

Fast Soft Recovery Rectifier Diode, 60 A



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| PRIMARY CHARACTERISTICS | | | | | | |
|----------------------------------|--------------------------|--|--|--|--|--|
| I _{F(AV)} | 60 A | | | | | |
| V _R | 200 V, 400 V, 600 V | | | | | |
| V _F at I _F | 1.3 V | | | | | |
| I _{FSM} | 830 A | | | | | |
| t _{rr} | 70 ns | | | | | |
| T _J max. | 150 °C | | | | | |
| Package | TO-247AC 2L, TO-247AC 3L | | | | | |
| Circuit configuration | Single | | | | | |
| Snap factor | 0.5 | | | | | |

FEATURES

- · Glass passivated pellet chip junction
- 150 °C max. operating junction temperature
- · Low forward voltage drop and short reverse recovery time
- **BoHS** COMPLIANT HALOGEN FREE
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-65EPF006-M3and VS-65APF006-M3 soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | |
|-------------------------------------|------------------------------|-------------|----|--|--|--|--|--|
| SYMBOL CHARACTERISTICS VALUES UNITS | | | | | | | | |
| V _{RRM} | | 200 to 600 | V | | | | | |
| I _{F(AV)} | Sinusoidal waveform | 60 | ٨ | | | | | |
| I _{FSM} | | 830 | A | | | | | |
| t _{rr} | 1 A, 100 A/µs | 70 | ns | | | | | |
| V _F | 30 A, T _J = 25 °C | 1.1 | V | | | | | |
| TJ | | -40 to +150 | °C | | | | | |

| VOLTAGE RATINGS | | | | | | | |
|------------------------------|---|--|-------------------------------------|--|--|--|--|
| PART NUMBER | V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} AT 150 °C mA | | | | |
| VS-60EPF02-M3, VS-60APF02-M3 | 200 | 300 | | | | | |
| VS-60EPF04-M3, VS-60APF04-M3 | 400 | 500 | 10 | | | | |
| VS-60EPF06-M3, VS-60APF06-M3 | 600 | 700 | | | | | |

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| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|--|------------------|---|--------|------------------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Maximum average forward current I _{F(AV)} | | $T_{C} = 106 \text{ °C}, 180^{\circ} \text{ conduction half sine wave}$ | 60 | | | | |
| Maximum peak one cycle | I _{FSM} | 10 ms sine pulse, rated V _{RRM} applied 700 | | A | | | |
| non-repetitive surge current | | 10 ms sine pulse, no voltage reapplied | 830 | | | | |
| Maximum I ² t for fusing | l ² t | 10 ms sine pulse, rated V _{RRM} applied | 2450 | A ² s | | | |
| Maximum - tior lusing | | 10 ms sine pulse, no voltage reapplied 3460 | | A-5 | | | |
| Maximum I²√t for fusing | l²√t | t = 0.1 ms to 10 ms, no voltage reapplied | 34 600 | A²√s | | | |

| ELECTRICAL SPECIFICATIONS | | | | | | | |
|---------------------------------|--------------------|------------------------------|-----------------------|--------|-------|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS | | |
| Maximum forward voltage drop | V _{FM} | 60 A, T _J = 25 °C | | 1.3 | V | | |
| Forward slope resistance | r _t | T.I = 150 °C | | 5.0 | mΩ | | |
| Threshold voltage | V _{F(TO)} | 1j = 150 C | | 0.88 | V | | |
| | I _{RM} | T _J = 25 °C | | 0.1 | | | |
| Maximum reverse leakage current | | T _J = 150 °C | $V_R = Rated V_{RRM}$ | 10 | mA | | |

| RECOVERY CHARACTERISTICS | | | | | | | |
|--------------------------|-----------------|---|--------|-------|--------------------------------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | · • | | |
| Reverse recovery time | t _{rr} | l∈ at 60 A _{nk} | 180 | ns | I _{FM} t | | |
| Reverse recovery current | I _{rr} | l _F at 60 A _{pk} 25 A/μs | 3.4 | А | $t_a \mid t_b$ | | |
| Reverse recovery charge | Q _{rr} | 25 °C | 0.5 | μC | $\frac{\text{dir}}{\text{dt}}$ | | |
| Snap factor | S | Typical | 0.5 | | dt I _{RM(REC)} | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|---|---------|-----------------------------------|--------------------------------------|-------------|------------|--|--|
| PARAMETER | | SYMBOL TEST CONDITIONS | | VALUES | UNITS | | |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | | -40 to +150 | °C | | |
| Maximum thermal resist junction to case | ance, | R _{thJC} | DC operation | 0.4 | | | |
| Maximum thermal resistance, junction to ambient | | R _{thJA} | | 40 | °C/W | | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased | 0.2 | | | |
| Approximate weight | | | | 6 | g | | |
| | | | | 0.21 | oz. | | |
| Mounting torque | minimum | | | 6 (5) | kgf ⋅ cm | | |
| Mounting torque | maximum | | | 12 (10) | (lbf · in) | | |
| | | | | 60EP | F02 | | |
| | | | Case style TO-247AC 2L | 60EPF04 | | | |
| Marking device | | | | 60EP | F06 | | |
| | | | | 60APF02 | | | |
| | | | Case style TO-247AC 3L | 60APF04 | | | |
| | | | | 60AP | F06 | | |

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150

140

130

120

110

100

90

0

10

20

30

Maximum Allowable Case

Temperature (°C)

60.PF. Series R_{thJC} (DC) = 0.4 K/W Maximum Average Forward Ø Conduction angle

120

180

60

70

Peak Half Sine Wave

Peak Half Sine Wave

90

50

60

40

Average Forward Current (A)

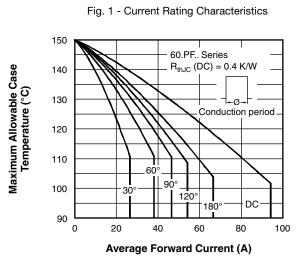


Fig. 2 - Current Rating Characteristics

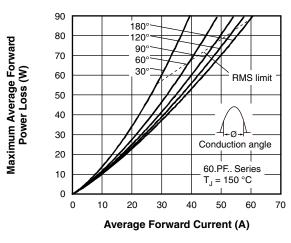
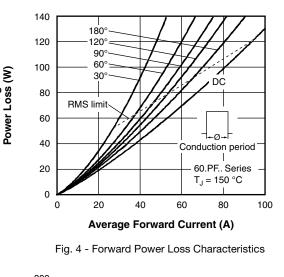
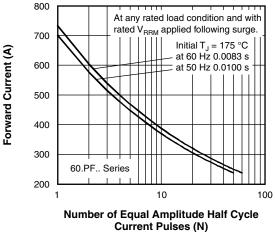


Fig. 3 - Forward Power Loss Characteristics

VS-60.PF0.-M3 Series

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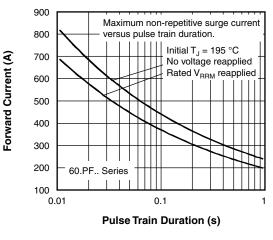


Fig. 6 - Maximum Non-Repetitive Surge Current

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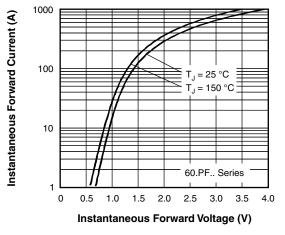
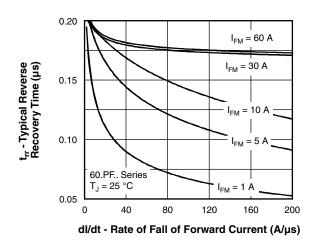


Fig. 7 - Forward Voltage Drop Characteristics



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Fig. 8 - Recovery Time Characteristics, T_J = 25 °C

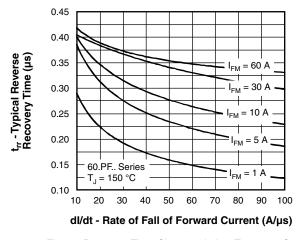


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C

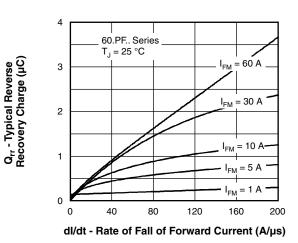


Fig. 10 - Recovery Charge Characteristics, T_J = 25 °C

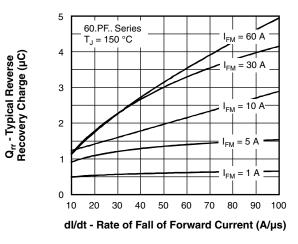


Fig. 11 - Recovery Charge Characteristics, T_J = 150 °C

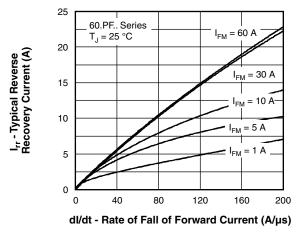
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Fig. 12 - Recovery Current Characteristics, $T_J = 25 \ ^{\circ}C$

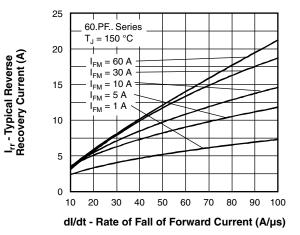


Fig. 13 - Recovery Current Characteristics, $T_J = 150$ °C

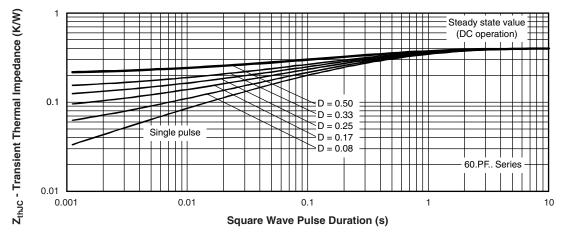


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device

VISHAY

| code | vs- | | 60 | Е | Р | F | 06 | -M3 | | |
|------|-----|---------------------------------|------------|---|------------|------------|------------|----------|--|--|
| | | | (2) | (3) | (4) | (5) | 6 | (7) | | |
| | | | \bigcirc | \bigcirc | \bigcirc | \bigcirc | \bigcirc | (| | |
| | 1 | - Vishay Semiconductors product | | | | | | | | |
| | 3 | | | | | | | | | |
| | | | | E = single diode, 2 pins | | | | | | |
| | _ | | A = | A = single diode, 3 pins | | | | | | |
| | 4 | - | | Package: | | | | | | |
| | | | | P = TO-247AC 3L / TO-247AC 2L | | | | | | |
| | 5 | - | | Type of silicon: | | | | | | |
| | 6 | _ | | F = fast recovery 02 = 200 V Voltage code x 100 = V _{RRM} 04 = 400 V | | | | | | |
| | 7 | - | | - | ital digit | | I | 06 = | | |
| | | | -M3 | = halog | en-free | RoHS- | complia | ant, and | | |

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-60EPF02-M3 | 25 | 500 | Antistatic plastic tubes | | | | |
| VS-60APF02-M3 | 25 | 500 | Antistatic plastic tubes | | | | |
| VS-60EPF04-M3 | 25 | 500 | Antistatic plastic tubes | | | | |
| VS-60APF04-M3 | 25 | 500 | Antistatic plastic tubes | | | | |
| VS-60EPF06-M3 | 25 | 500 | Antistatic plastic tubes | | | | |
| VS-60APF06-M3 | 25 | 500 | Antistatic plastic tubes | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|-------------|--------------------------|--|--|--|--|
| Dimensions | TO-247AC 2L | www.vishay.com/doc?96144 | | | | |
| Dimensions | TO-247AC 3L | www.vishay.com/doc?96138 | | | | |
| Part marking information | TO-247AC 2L | www.vishay.com/doc?95648 | | | | |
| Part marking information | TO-247AC 3L | www.vishay.com/doc?95007 | | | | |
| SPICE model | | www.vishay.com/doc?95275 | | | | |

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